

isc Silicon NPN Power Transistor

2SC3353

DESCRIPTION

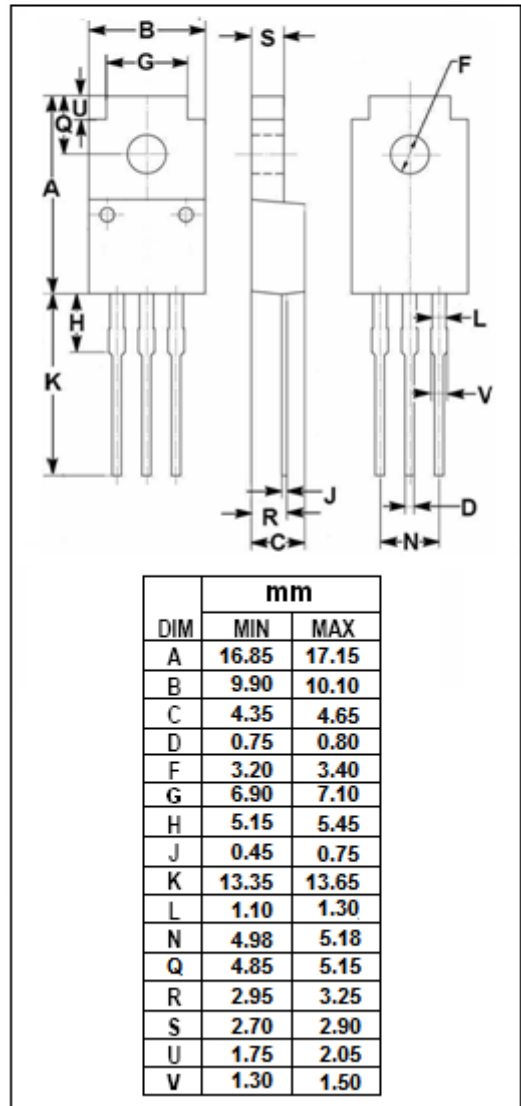
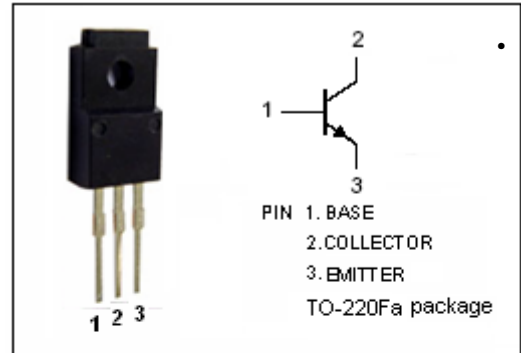
- Collector-Emitter Sustaining Voltage-
: $V_{CEO(SUS)} = 500V(\text{Min.})$
- Low Collector Saturation Voltage
: $V_{CE(sat)} = 1.0V(\text{Max.}) @ I_C = 3A$
- High Speed Switching

APPLICATIONS

- Designed for high speed switching applications.

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ C$)

| SYMBOL | PARAMETER | VALUE | UNIT |
|-----------|---|---------|------------|
| V_{CBO} | Collector-Base Voltage | 800 | V |
| V_{CEO} | Collector-Emitter Voltage | 500 | V |
| V_{EBO} | Emitter-Base Voltage | 8 | V |
| I_C | Collector Current-Continuous | 5 | A |
| I_{CM} | Collector Current-Peak | 10 | A |
| I_B | Base Current-Continuous | 3 | A |
| P_C | Collector Power Dissipation @ $T_a = 25^\circ C$ | 2 | W |
| | Collector Power Dissipation @ $T_C = 25^\circ C$ | 40 | |
| T_j | Junction Temperature | 150 | $^\circ C$ |
| T_{stg} | Storage Temperature Range | -55~150 | $^\circ C$ |



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ELECTRICAL CHARACTERISTICS

 $T_C=25^{\circ}\text{C}$ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | MAX | UNIT |
|----------------|--------------------------------------|---|-----|------|-----|------|
| $V_{CEO(SUS)}$ | Collector-Emitter Sustaining Voltage | $I_C=0.2\text{A}$; $L=25\text{mH}$ | 500 | | | V |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C=3\text{A}$; $I_B=0.6\text{A}$ | | | 1.0 | V |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage | $I_C=3\text{A}$; $I_B=0.6\text{A}$ | | | 1.5 | V |
| I_{CBO} | Collector Cutoff Current | $V_{CB}=800\text{V}$; $I_E=0$ | | | 0.1 | mA |
| I_{EBO} | Emitter Cutoff Current | $V_{EB}=5\text{V}$; $I_C=0$ | | | 0.1 | mA |
| h_{FE-1} | DC Current Gain | $I_C=0.1\text{A}$; $V_{CE}=5\text{V}$ | 15 | | | |
| h_{FE-2} | DC Current Gain | $I_C=3\text{A}$; $V_{CE}=5\text{V}$ | 8 | | | |
| f_T | Current-Gain—Bandwidth Product | $I_C=0.5\text{A}$; $V_{CE}=10\text{V}$ | | 3 | | MHz |

Switching Times; Resistive Load

| | | | | | | |
|----------|--------------|--|--|--|-----|---------------|
| t_{on} | Turn-on Time | $I_C=3\text{A}$; $I_{B1}=-I_{B2}=0.6\text{A}$; $V_{CC}=200\text{V}$ | | | 1.0 | μs |
| t_s | Storage Time | | | | 3.0 | μs |
| t_f | Fall Time | | | | 1.0 | μs |